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## In the Claims:

Claim 1 and 2 are amended herein. Claim 10 is canceled.

Non-elected claims 5-9 were previously canceled. The remaining claims are not amended in this response.

- 1. (currently amended) A mask blank used for the charged-particle beam exposure charged particle beam exposure stencil mask comprising a silicon membrane defining through-holes for transmitting charged particle beams, which is made by employing an SOI substrate having a front-side silicon membrane and a back-side silicon layer with a silicon oxide film having a first internal stress interposed therebetween, wherein the back-side silicon layer of said SOI substrate and the silicon oxide film are partially removed to form an opening to be an exposed region and an etching stop layer, which is removed at the time of mask processing, having lower internal stress than said first internal stress is formed in the opening.
- 2. (currently amended) A mask blank used for the charged particle beam exposure as claimed in claim 1, wherein said etching stop layer is made of any one selected from the group consisting of Cr, [[Ti,]] Ta, Mo, W, and Zr and nitrides, oxides, and oxvnitrides of theses metals.
- 3. (original) A mask blank used for the charged particle beam exposure as claimed in claim 1 or 2, wherein a hard mask

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layer made of any one selected from a group consisting of Cr, Ti,

Ta, Mo, W, and Zr and oxides, nitrides, and oxynitrides of these

metals is formed on the front-side silicon membrane of said mask

blank used for the charged particle beam exposure.

4. (original) A mask blank used for the charged particle

beam exposure as claimed in claim 3, wherein said etching stop

layer and said hard mask layer are made of the same material.

5. (canceled)

6. (canceled)

(canceled)

(canceled) 8.

9. (canceled)

10. (canceled)

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